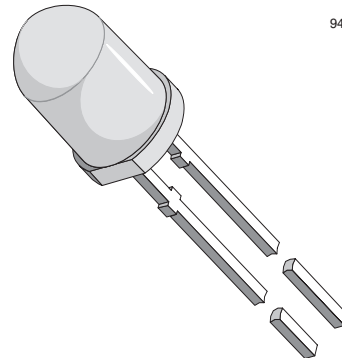


Ultrabright LED, \varnothing 5 mm Untinted Non-Diffused

Description

The TLC.58.. series is a clear, non diffused 5 mm LED for high end applications where supreme luminous intensity and a very small emission angle is required. These lamps with clear untinted plastic case utilize the highly developed ultrabright AllnGaP and GaP technologies.

The very small viewing angle of these devices provide a very high luminous intensity.



94 8631

Features

- Untinted non diffused lens
- Utilizing ultrabright AllnGaP and InGaN technology
- Very high luminous intensity
- Very small emission angle
- High operating temperature: T_j (chip junction temperature) up to 125 °C for AllnGaP devices
- Luminous intensity and color categorized for each packing unit
- ESD-withstand voltage: 2 kV acc. to MIL STD 883 D, Method 3015.7 for AllnGaP, 1 kV for InGaN

Applications

- Interior and exterior lighting
- Outdoor LED panels, displays
- Instrumentation and front panel indicators
- Central high mounted stop lights (CHMSL) for motor vehicles
- Replaces incandescent lamps
- Traffic signals and signs
- Light guide design

Parts Table

Part	Color, Luminous Intensity	Technology
TLCR5800	Red, $I_V > 7500$ mcd	AllGaP on GaAs
TLCY5800	Yellow, $I_V > 5750$ mcd	AllGaP on GaAs
TLCTG5800	True green, $I_V > 2400$ mcd	InGaN on SiC
TLCB5800	Blue, $I_V > 750$ mcd	InGaN on SiC

Absolute Maximum Ratings

$T_{amb} = 25$ °C, unless otherwise specified

TLCR5800 , TLCY5800 , TLCTG5800 , TLCB5800

Parameter	Test condition	Part	Symbol	Value	Unit
Reverse voltage			V_R	5	V
DC forward current	$T_{amb} \leq 85$ °C	TLCR5800	I_F	50	mA
	$T_{amb} \leq 85$ °C	TLCY5800	I_F	50	mA
	$T_{amb} \leq 60$ °C	TLCTG5800	I_F	30	mA
	$T_{amb} \leq 60$ °C	TLCTG5800	I_F	30	mA

Parameter	Test condition	Part	Symbol	Value	Unit
Surge forward current	$t_p \leq 10 \mu s$	TLCR5800	I_{FSM}	1	A
	$t_p \leq 10 \mu s$	TLCR5800	I_{FSM}	1	A
	$t_p \leq 10 \mu s$	TLCTG5800	I_{FSM}	0.1	A
	$t_p \leq 10 \mu s$	TLCTG5800	I_{FSM}	0.1	A
Power dissipation	$T_{amb} \leq 85^\circ C$	TLCR5800	P_V	135	mW
	$T_{amb} \leq 85^\circ C$	TLCR5800	P_V	135	mW
	$T_{amb} \leq 60^\circ C$	TLCTG5800	P_V	135	mW
	$T_{amb} \leq 60^\circ C$	TLCTG5800	P_V	135	mW
Junction temperature		TLCR5800	T_j	125	$^\circ C$
		TLCR5800	T_j	125	$^\circ C$
		TLCTG5800	T_j	100	$^\circ C$
		TLCTG5800	T_j	100	$^\circ C$
Operating temperature range			T_{amb}	- 40 to + 100	$^\circ C$
Storage temperature range			T_{stg}	- 40 to + 100	$^\circ C$
Soldering temperature	$t \leq 5 s, 2 mm$ from body		T_{sd}	260	$^\circ C$
Thermal resistance junction/ambient			R_{thJA}	300	K/W

Optical and Electrical Characteristics

$T_{amb} = 25^\circ C$, unless otherwise specified

Red

TLCR5800

Parameter	Test condition	Part	Symbol	Min	Typ.	Max	Unit
Luminous intensity ¹⁾	$I_F = 50 mA$	TLCR5800	I_V	7500	20000		
Dominant wavelength	$I_F = 50 mA$		λ_d	611	616	622	nm
Peak wavelength	$I_F = 50 mA$		λ_p		622		nm
Spectral bandwidth at 50 % $I_{rel max}$	$I_F = 50 mA$		$\Delta\lambda$		18		nm
Angle of half intensity	$I_F = 50 mA$		ϕ		± 4		deg
Forward voltage	$I_F = 50 mA$		V_F		2.1	2.7	V
Reverse voltage	$I_R = 10 \mu A$		V_R	5			V
Temperature coefficient of V_F	$I_F = 50 mA$		TC_{VF}		- 3.5		mV/K
Temperature coefficient of λ_d	$I_F = 50 mA$		$TC_{\lambda d}$		0.05		nm/K

¹⁾ in one Packing Unit $I_{VMax}/I_{VMin} \leq 1.6$

Yellow
TLCY5800

Parameter	Test condition	Part	Symbol	Min	Typ.	Max	Unit
Luminous intensity ¹⁾	$I_F = 50 \text{ mA}$	TLCY5800	I_V	5750	14000		mcd
Dominant wavelength	$I_F = 50 \text{ mA}$		λ_d	585	590	597	nm
Peak wavelength	$I_F = 50 \text{ mA}$		λ_p		593		nm
Spectral bandwidth at 50 % I_{rel} max	$I_F = 50 \text{ mA}$		$\Delta\lambda$		17		nm
Angle of half intensity	$I_F = 50 \text{ mA}$		φ		± 4		deg
Forward voltage	$I_F = 50 \text{ mA}$		V_F		2.1	2.7	V
Reverse voltage	$I_R = 10 \mu\text{A}$		V_R	5			V
Temperature coefficient of V_F	$I_F = 50 \text{ mA}$		TC_{V_F}		- 3.5		mV/K
Temperature coefficient of λ_d	$I_F = 50 \text{ mA}$		TC_{λ_d}		0.1		nm/K

¹⁾ in one Packing Unit $I_{V_{Max}}/I_{V_{Min}} \leq 1.6$

Pure green

Parameter	Test condition	Part	Symbol	Min	Typ.	Max	Unit
Luminous intensity ¹⁾	$I_F = 30 \text{ mA}$	TLCTG5800	I_V	2400	7000		mcd
Dominant wavelength	$I_F = 30 \text{ mA}$		λ_d	515	525	535	nm
Peak wavelength	$I_F = 30 \text{ mA}$		λ_p		520		nm
Spectral bandwidth at 50 % I_{rel} max	$I_F = 30 \text{ mA}$		$\Delta\lambda$		37		nm
Angle of half intensity	$I_F = 30 \text{ mA}$		φ		± 4		deg
Forward voltage	$I_F = 30 \text{ mA}$		V_F		3.9	4.5	V
Reverse voltage	$I_R = 10 \mu\text{A}$		V_R	5			V
Temperature coefficient of V_F	$I_F = 30 \text{ mA}$		TC_{V_F}		- 4.5		mV/K
Temperature coefficient of λ_d	$I_F = 30 \text{ mA}$		TC_{λ_d}		0.02		nm/K

¹⁾ in one Packing Unit $I_{V_{Max}}/I_{V_{Min}} \leq 1.6$

Blue
TLCB5800

Parameter	Test condition	Part	Symbol	Min	Typ.	Max	Unit
Luminous intensity ¹⁾	$I_F = 30 \text{ mA}$	TLCB5800	I_V	750	2500		mcd
Dominant wavelength	$I_F = 30 \text{ mA}$		λ_d	462	470	476	nm
Peak wavelength	$I_F = 30 \text{ mA}$		λ_p		464		nm
Spectral bandwidth at 50 % I_{rel} max	$I_F = 30 \text{ mA}$		$\Delta\lambda$		25		nm
Angle of half intensity	$I_F = 30 \text{ mA}$		φ		± 4		deg
Forward voltage	$I_F = 30 \text{ mA}$		V_F		3.9	4.5	V
Reverse voltage	$I_R = 10 \mu\text{A}$		V_R	5			V
Temperature coefficient of V_F	$I_F = 30 \text{ mA}$		TC_{V_F}		- 5.0		mV/K
Temperature coefficient of λ_d	$I_F = 30 \text{ mA}$		TC_{λ_d}		0.02		nm/K

¹⁾ in one Packing Unit $I_{V_{Max}}/I_{V_{Min}} \leq 1.6$

Typical Characteristics ($T_{amb} = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)

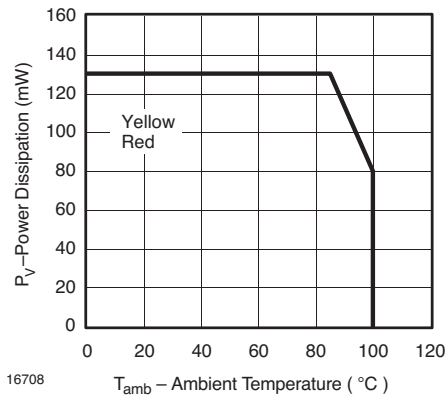


Figure 1. Power Dissipation vs. Ambient Temperature

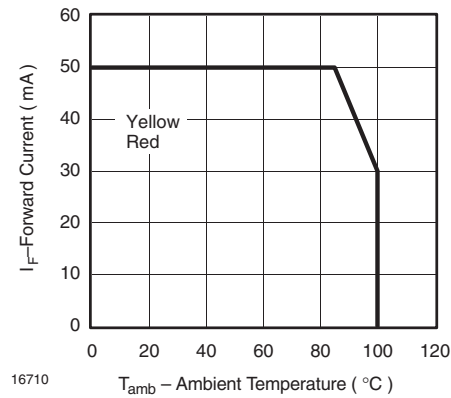


Figure 4. Forward Current vs. Ambient Temperature

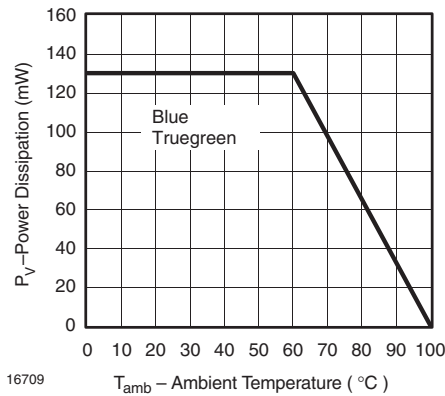


Figure 2. Power Dissipation vs. Ambient Temperature

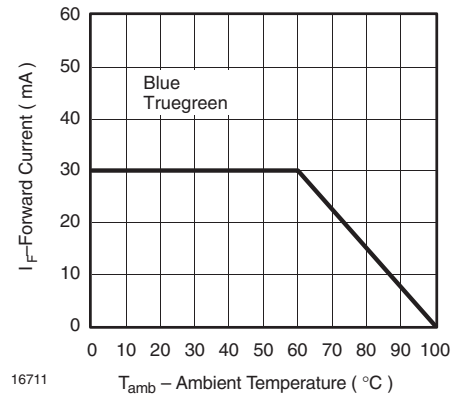


Figure 5. Forward Current vs. Ambient Temperature

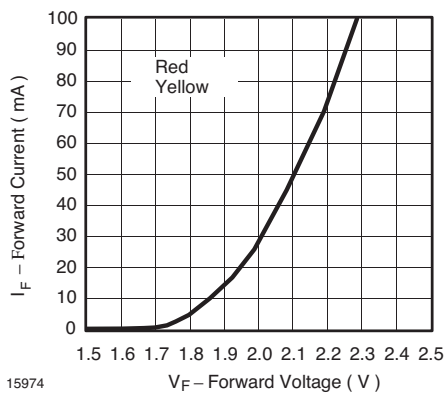


Figure 3. Forward Current vs. Forward Voltage

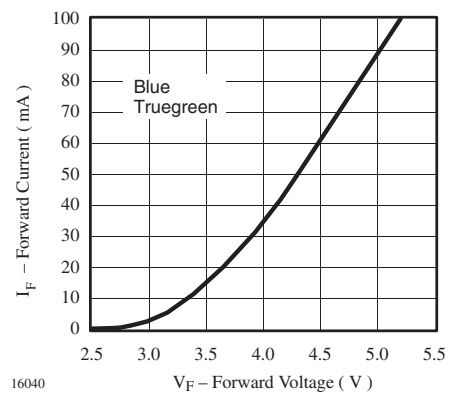


Figure 6. Forward Current vs. Forward Voltage

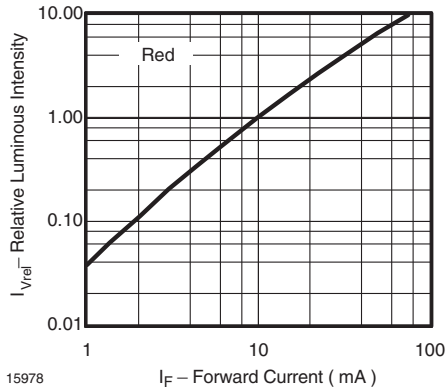


Figure 7. Relative Luminous Flux vs. Forward Current

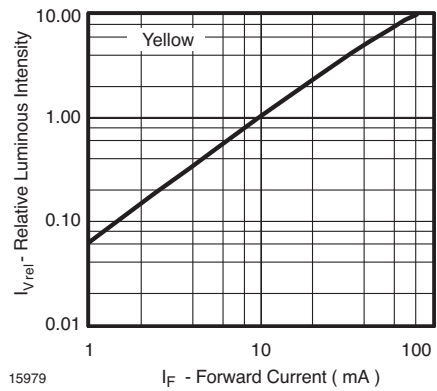


Figure 10. Relative Luminous Flux vs. Forward Current

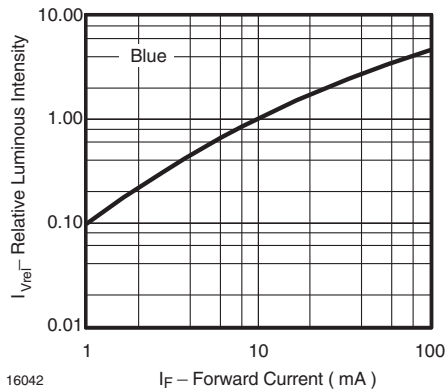


Figure 8. Relative Luminous Flux vs. Forward Current

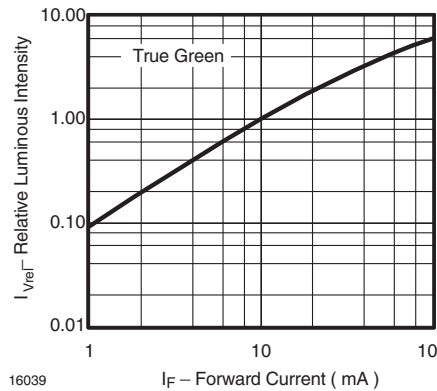


Figure 11. Relative Luminous Flux vs. Forward Current

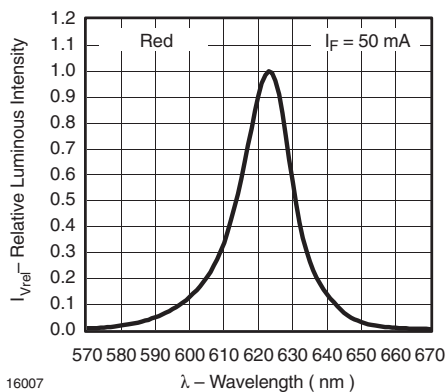


Figure 9. Relative Intensity vs. Wavelength

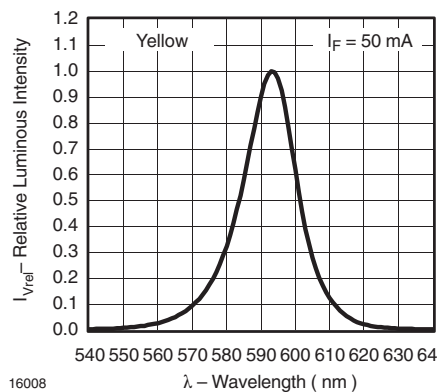


Figure 12. Relative Intensity vs. Wavelength

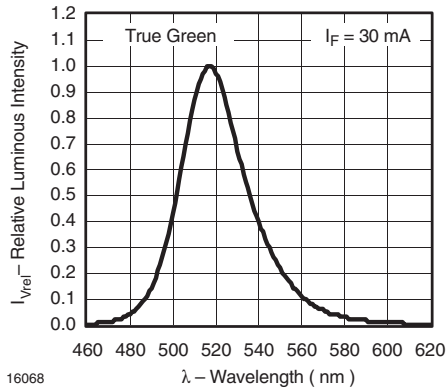


Figure 13. Relative Intensity vs. Wavelength

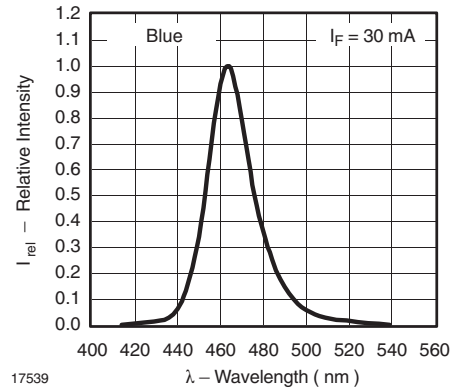
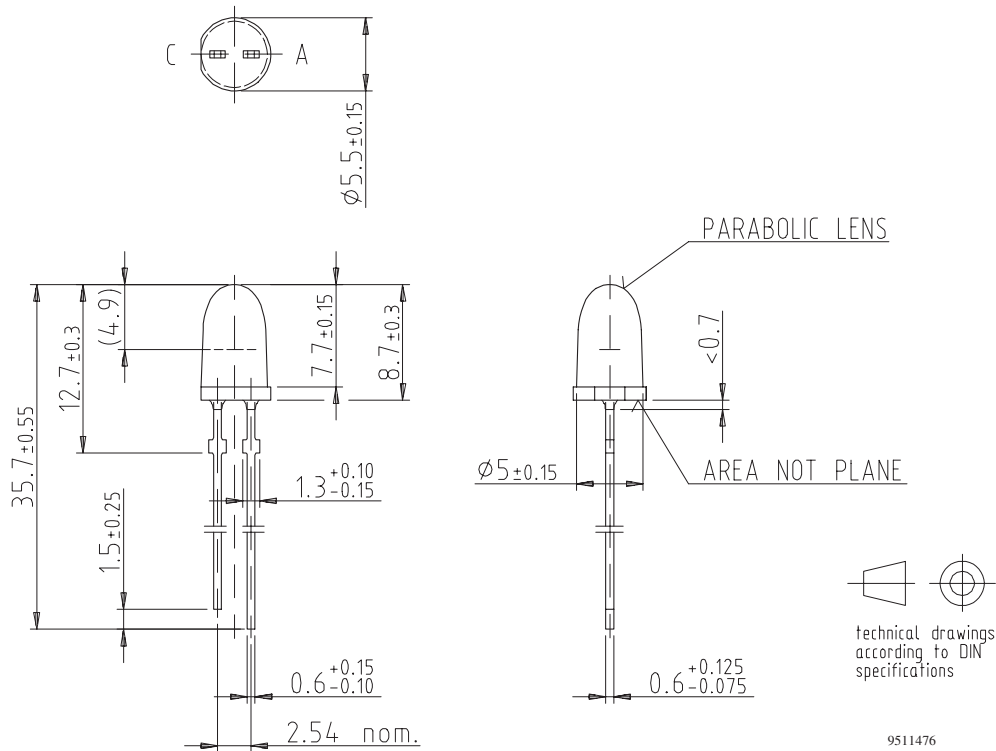


Figure 14. Relative Intensity vs. Wavelength

Package Dimensions in mm



Ozone Depleting Substances Policy Statement

It is the policy of **Vishay Semiconductor GmbH** to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

**We reserve the right to make changes to improve technical design
and may do so without further notice.**

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany
Telephone: 49 (0)7131 67 2831, Fax number: 49 (0)7131 67 2423

Компания «Life Electronics» занимается поставками электронных компонентов импортного и отечественного производства от производителей и со складов крупных дистрибьюторов Европы, Америки и Азии.

С конца 2013 года компания активно расширяет линейку поставок компонентов по направлению коаксиальный кабель, кварцевые генераторы и конденсаторы (керамические, пленочные, электролитические), за счёт заключения дистрибьюторских договоров

Мы предлагаем:

- Конкурентоспособные цены и скидки постоянным клиентам.
- Специальные условия для постоянных клиентов.
- Подбор аналогов.
- Поставку компонентов в любых объемах, удовлетворяющих вашим потребностям.
- Приемлемые сроки поставки, возможна ускоренная поставка.
- Доставку товара в любую точку России и стран СНГ.
- Комплексную поставку.
- Работу по проектам и поставку образцов.
- Формирование склада под заказчика.
- Сертификаты соответствия на поставляемую продукцию (по желанию клиента).
- Тестирование поставляемой продукции.
- Поставку компонентов, требующих военную и космическую приемку.
- Входной контроль качества.
- Наличие сертификата ISO.

В составе нашей компании организован Конструкторский отдел, призванный помогать разработчикам, и инженерам.

Конструкторский отдел помогает осуществить:

- Регистрацию проекта у производителя компонентов.
- Техническую поддержку проекта.
- Защиту от снятия компонента с производства.
- Оценку стоимости проекта по компонентам.
- Изготовление тестовой платы монтаж и пусконаладочные работы.



Тел: +7 (812) 336 43 04 (многоканальный)

Email: org@lifeelectronics.ru